

# MOTOROLA SEMICONDUCTOR TECHNICAL DATA

## MDA3500 Series

### RECTIFIER ASSEMBLY

... utilizing individual void-free molded MR2500 Series rectifiers, interconnected and mounted on an electrically isolated aluminum heat sink by a high thermal-conductive epoxy resin.

- 400 Ampere Surge Capability
- Electrically Isolated Base — 1800 Volts
- UL Recognized
- Cost Effective in Lower Current Applications



### SINGLE-PHASE FULL-WAVE BRIDGE

35 AMPERES  
50-1000 VOLTS

### MAXIMUM RATINGS

| Rating (Per Diode)                                                                                       | Symbol         | MDA         |      |      |      |      |      |      | Unit             |
|----------------------------------------------------------------------------------------------------------|----------------|-------------|------|------|------|------|------|------|------------------|
|                                                                                                          |                | 3500        | 3501 | 3502 | 3504 | 3506 | 3508 | 3510 |                  |
| Peak Repetitive Reverse Voltage                                                                          | $V_{RRM}$      | 50          | 100  | 200  | 400  | 600  | 800  | 1000 | Volts            |
| Working Peak Reverse Voltage                                                                             | $V_{RWM}$      |             |      |      |      |      |      |      |                  |
| DC Blocking Voltage                                                                                      | $V_R$          |             |      |      |      |      |      |      |                  |
| DC Output Voltage                                                                                        |                |             |      |      |      |      |      |      |                  |
| Resistive Load                                                                                           | $V_{dc}$       | 30          | 62   | 124  | 250  | 380  | 500  | 630  | Volts            |
| Capacitive Load                                                                                          | $V_{dc}$       | 50          | 100  | 200  | 400  | 600  | 800  | 1000 | Volts            |
| Sine Wave RMS Input Voltage                                                                              | $V_R$ (RMS)    | 35          | 70   | 140  | 280  | 420  | 560  | 700  | Volts            |
| Average Rectified Forward Current (Single phase bridge resistive load, 60 Hz, $T_C = 55^\circ\text{C}$ ) | $I_O$          | 35          |      |      |      |      |      |      | Amp              |
| Non-Repetitive Peak Surge Current (Surge applied at rated load conditions)                               | $I_{FSM}$      | 400         |      |      |      |      |      |      | Amp              |
| Operating and Storage Junction Temperature Range                                                         | $T_J, T_{stg}$ | -65 to +175 |      |      |      |      |      |      | $^\circ\text{C}$ |

### THERMAL CHARACTERISTICS (Total Bridge)

| Characteristic                       | Symbol          | Typ | Max  | Unit               |
|--------------------------------------|-----------------|-----|------|--------------------|
| Thermal Resistance, Junction to Case | $R_{\theta JC}$ | 1.4 | 1.87 | $^\circ\text{C/W}$ |

### ELECTRICAL CHARACTERISTICS ( $T_C = 25^\circ\text{C}$ unless otherwise noted).

| Characteristic                                                                 | Symbol | Min | Typ | Max | Unit          |
|--------------------------------------------------------------------------------|--------|-----|-----|-----|---------------|
| Instantaneous Forward Voltage (Per Diode) ( $I_F = 55\text{ A}$ ) <sup>*</sup> | $V_F$  | —   | 1.0 | 1.1 | Volts         |
| Reverse Current (Per Diode) (Rated $V_R$ )                                     | $I_R$  | —   | —   | 10  | $\mu\text{A}$ |

### MECHANICAL CHARACTERISTICS

**CASE:** Plastic case with an electrically isolated aluminum base.

**POLARITY:** Terminal designation embossed on case:

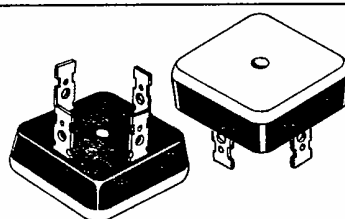
- + DC output
- DC output
- AC not marked

**MOUNTING POSITION:** Bolt down. Highest heat transfer efficiency accomplished through the surface opposite the terminals. Use silicone grease on mounting surface for maximum heat transfer.

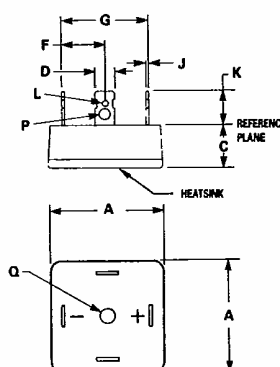
**WEIGHT:** 40 grams (approx.)

**TERMINALS:** Suitable for fast-on connections. Readily solderable, corrosion resistant. Soldering recommended for applications greater than 15 amperes.

**MOUNTING TORQUE:** 20 in-lb max



3



#### NOTES:

1. DIMENSION "Q" SHALL BE MEASURED ON HEATSINK SIDE OF PACKAGE.
2. DIMENSIONS F AND G SHALL BE MEASURED AT THE REFERENCE PLANE.

| DIM | MILLIMETERS |       | INCHES |       |
|-----|-------------|-------|--------|-------|
|     | MIN         | MAX   | MIN    | MAX   |
| A   | 34.80       | 35.18 | 1.370  | 1.385 |
| C   | 12.44       | 13.97 | 0.490  | 0.550 |
| D   | 6.10        | 6.60  | 0.240  | 0.260 |
| F   | 13.97       | 14.50 | 0.550  | 0.571 |
| G   | 28.00       | 29.00 | 1.100  | 1.142 |
| J   | 0.71        | 0.86  | 0.028  | 0.034 |
| K   | 9.52        | 11.43 | 0.375  | 0.450 |
| L   | 1.52        | 2.06  | 0.060  | 0.081 |
| P   | 2.79        | 2.92  | 0.110  | 0.115 |
| Q   | 4.32        | 4.83  | 0.170  | 0.190 |

CASE 309A-02

<sup>\*</sup>Pulse Width = 100 ms, Duty Cycle ≤ 2%.

## MDA3500 Series

FIGURE 1 – FORWARD VOLTAGE

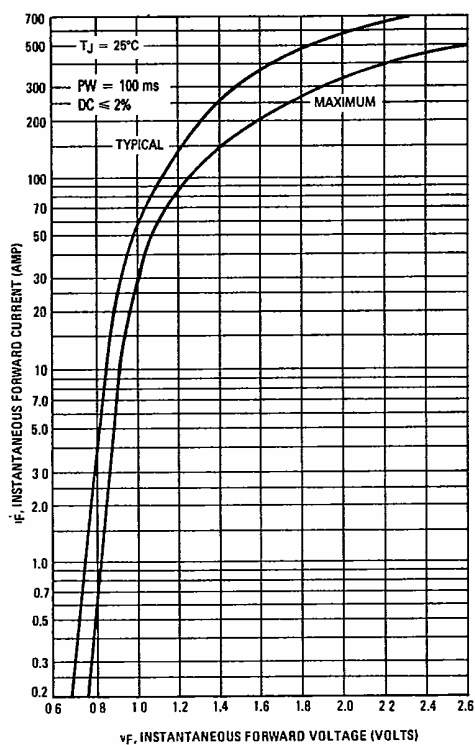


FIGURE 2 – NON REPETITIVE SURGE CURRENT

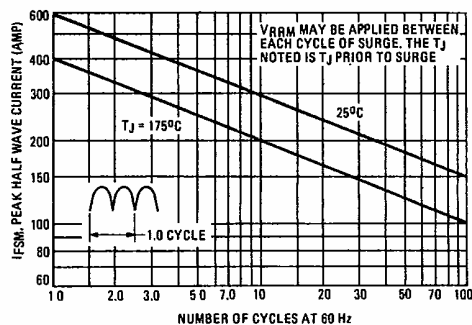


FIGURE 3 – FORWARD VOLTAGE TEMPERATURE COEFFICIENT

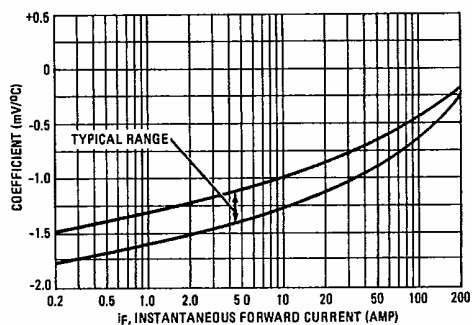


FIGURE 4 – CURRENT DERATING

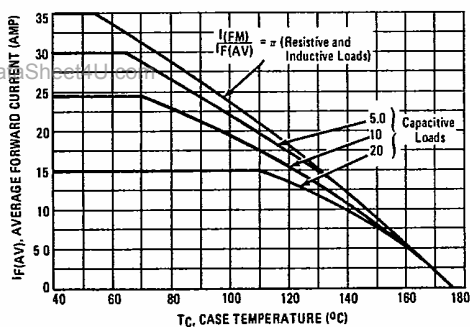
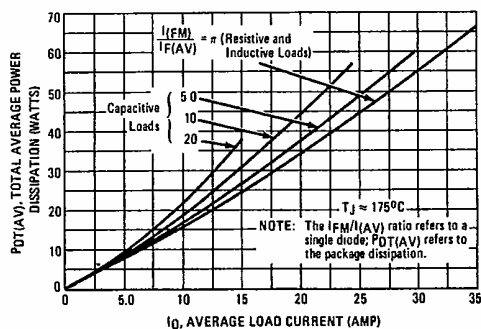
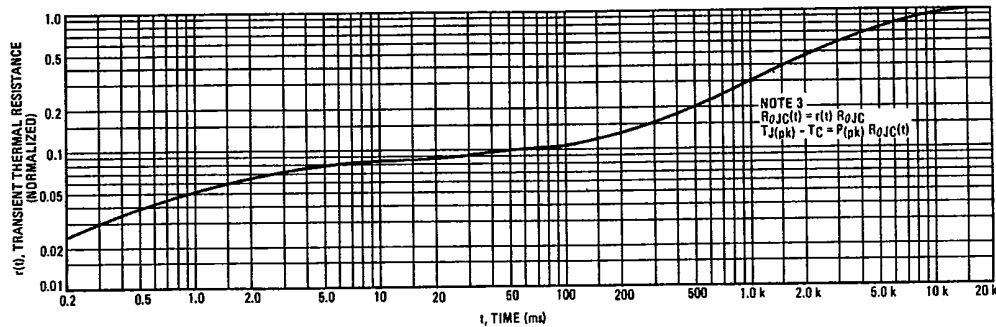


FIGURE 5 – FORWARD POWER DISSIPATION



## MDA3500 Series

FIGURE 6 -- TYPICAL THERMAL RESPONSE



NOTE 1

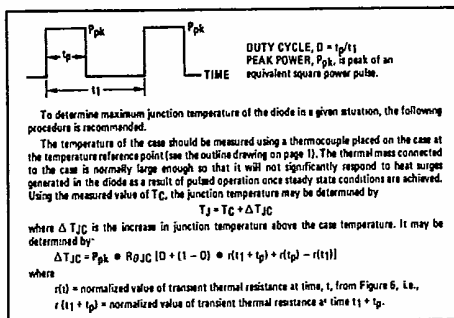


FIGURE 7 -- CAPACITANCE

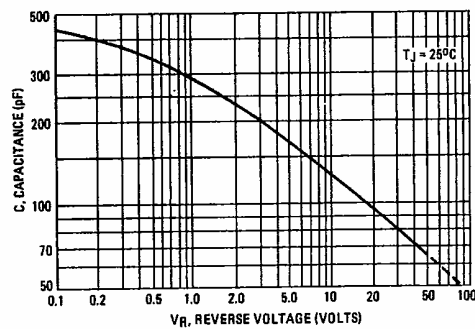


FIGURE 8 -- FORWARD RECOVERY TIME

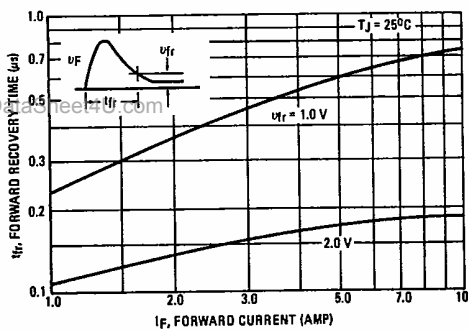
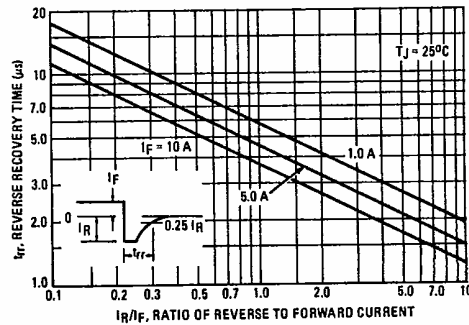


FIGURE 9 -- REVERSE RECOVERY TIME



## MDA3500 Series

## AMBIENT TEMPERATURE DERATING INFORMATION

FIGURE 10A – THERMALLOY HEATSINK 6005B

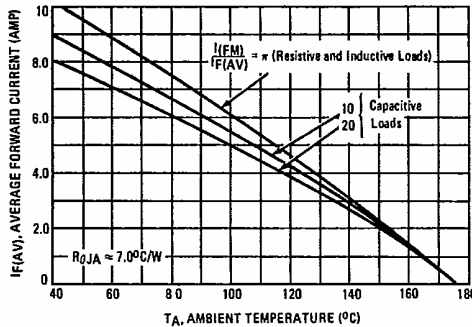
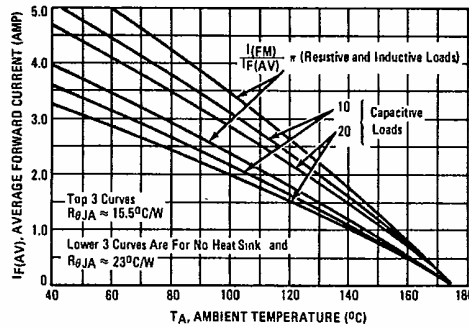


FIGURE 10B – IERC HEATSINK UP3 AND NO HEATSINK



## NOTE 2: THERMAL COUPLING AND EFFECTIVE THERMAL RESISTANCE

In multiple chip devices where there is coupling of heat between die, the junction temperature can be calculated as follows:

$$(1) \Delta T_{J1} = R_{\theta 1} P_{D1} + R_{\theta 2} K_{\theta 2} P_{D2} + R_{\theta 3} K_{\theta 3} P_{D3} + R_{\theta 4} K_{\theta 4} P_{D4}$$

Where  $\Delta T_{J1}$  is the change in junction temperature of diode 1  
 $R_{\theta 1}$  thru 4 is the thermal resistance of diodes 1 through 4  
 $P_{D1}$  thru 4 is the power dissipated in diodes 1 through 4  
 $K_{\theta 2}$  thru 4 is the thermal coupling between diode 1 and diodes 2 through 4.

An effective package thermal resistance can be defined as follows:

$$(2) R_{\theta(EFF)} = \Delta T_{J1} / P_{DT}$$

Where:  $P_{DT}$  is the total package power dissipation

Assuming equal thermal resistance for each die, equation (1) simplifies to

$$(3) \Delta T_{J1} = R_{\theta 1} (P_{D1} + K_{\theta 2} P_{D2} + K_{\theta 3} P_{D3} + K_{\theta 4} P_{D4})$$

For the conditions where  $P_{D1} = P_{D2} = P_{D3} = P_{D4}$ ,  $P_{DT} = 4 P_{D1}$ , equation (3) can be further simplified and by substituting into equation (2) results in

$$(4) R_{\theta(EFF)} = R_{\theta 1} (1 + K_{\theta 2} + K_{\theta 3} + K_{\theta 4}) / 4$$

When the case is used as a reference point, coupling between die is negligible for the MDA3500. When the bridge is used without heatsink, coupling between die is approximately 70% and  $R_{\theta 1}$  is 30°C/W.

$$\therefore R_{\theta(EFF)} = 30 [1 + (3)(.7)] / 4 = 23^\circ\text{C/W}$$

## NOTE 3: SPLIT LOAD DERATING INFORMATION

Bridge rectifiers are used in two basic configurations as shown by circuits A and B of Figure 11. The current derating data of Figure 4 applies to the standard bridge circuit (A) where  $I_A = I_B$ . For circuit B where  $I_A \neq I_B$ , derating information can be calculated as follows:

$$(6) T_R(\text{Max}) = T_J(\text{Max}) - \Delta T_{J1}$$

Where  $T_R(\text{Max})$  is the reference temperature (either case or ambient)

$\Delta T_{J1}$  can be calculated using equation (3) in Note 2.

For example, to determine  $T_C(\text{Max})$  for the MDA3500 with the following capacitive load conditions.

$I_A = 20$  A average with a peak of 60 A

$I_B = 10$  A average with a peak of 70 A

First calculate the peak to average ratio for  $I_A$ .  $I(pK)/I(AV) = 60/20 = 3.0$ . (Note that the peak to average ratio is on a per diode basis and each diode provides 10 A average).

From Figure 5, for an average current of 20 A and an  $I(pK)/I(AV) = 3.0$  read  $P_{DT(AV)} = 40$  watts or 10 watts/diode. Thus  $P_{D1} = P_{D3} = 10$  watts.

Similarly, for a load current  $I_B$  of 10 A, diode #2 and diode #4 each see 5.0 A average resulting in an  $I(pK)/I(AV) = 14$ .

Thus, the package power dissipation for 10 A is 20 watts or 5.0 watts/diode.  $\therefore P_{D2} = P_{D4} = 5.0$  watts.

The maximum junction temperature occurs in diode #1 and #3. From equation (3) for diode #1  $\Delta T_{J1} = (7.5)(10)$ , since coupling is negligible.

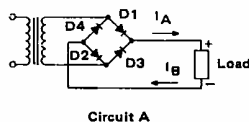
$$\Delta T_{J1} \approx 75^\circ\text{C}$$

$$\text{Thus } T_C(\text{Max}) = 175 - 75 = 100^\circ\text{C}$$

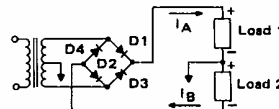
The total package dissipation in this example is:

$P_{DT(AV)} = 2 \times 10 + 2 \times 5.0 = 30$  watts, which must be considered when selecting a heat sink.

FIGURE 11– BASIC CIRCUIT USES FOR BRIDGE RECTIFIERS



Circuit A



Circuit B